

TLP3082(S)

- Office Machine
- Household Use Equipment
- Triac Driver
- Solid State Relay

The TOSHIBA TLP3082(S) consists of a zero voltage crossing turn-on photo-triac optically coupled to a GaAs infrared emitting diode in a six lead plastic DIP package.

Features

- Peak off-state voltage: 800V (Min.)
 - Trigger LED current: 10mA (Max.)
 - On-state current: 100mA (Max.)
 - Isolation voltage: 5000Vrms (Min.)
 - UL recognized: UL1577, file No. E67349
 - Option(D4) type
- VDE approved: DIN EN 60747-5-2

Certificate No. 40009302

Maximum operating insulation voltage : 890Vpk

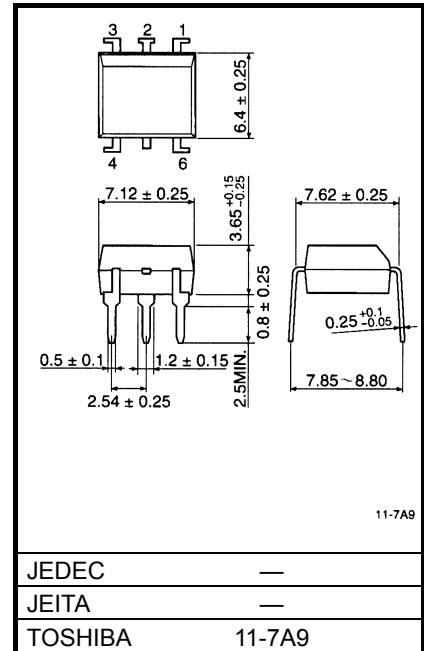
Highest permissible over voltage : 8000Vpk

(Note) When an EN60747-5-2 approved type is needed, please designate the "Option(D4)".

- Construction mechanical rating

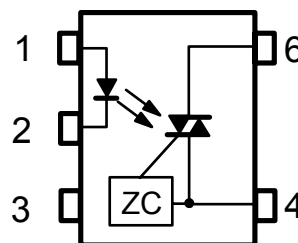
	7.62 mm pitch standard type	10.16 mm pitch TLPXXXXF type
Creepage distance	7.0 mm (Min.)	8.0 mm (Min.)
Clearance	7.0 mm (Min.)	8.0 mm (Min.)
Insulation thickness	0.4 mm (Min.)	0.4 mm (Min.)

Unit: mm



Weight: 0.39 g (Typ.)

Pin configuration (top view)



- 1: Anode
- 2: Cathode
- 3: N.C.
- 4: Terminal 1
- 6: Terminal 2

ZC: Zero-cross Circuit

(Note) When specifying the application type name for certification testing, be sure to use the standard product type name, e.g., TLP3082

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
LED	Forward current	I_F	50	mA	
	Forward current derating (Ta≥53°C)	$\Delta I_F / ^\circ\text{C}$	-0.7	mA / °C	
	Peak forward current (100μs pulse, 100pps)	I_{FP}	1	A	
	Reverse voltage	V_R	5	V	
	Junction temperature	T_J	125	°C	
Detector	Off-state output terminal voltage	V_{DRM}	800	V	
	On-state RMS current	Ta=25°C	$I_{T(RMS)}$	100	mA
		Ta=70°C		50	
	On-state current derating (Ta≥25°C)	$\Delta I_T / ^\circ\text{C}$	-1.1	mA / °C	
	Peak on-state current (100μs pulse, 120pps)	I_{TP}	2	A	
	Peak nonrepetitive surge current (Pw=10ms,DC=10%)	I_{TSM}	1.2	A	
	Junction temperature	T_j	115	°C	
Storage temperature range	T_{stg}	-55~125	°C		
Operating temperature range	T_{opr}	-40~100	°C		
Lead soldering temperature (10s)	T_{sol}	260	°C		
Isolation voltage (AC, 1min. , R.H. ≤60%)	(Note 1) BV_S	5000	Vrms		

(Note 1) Device considered a two terminal device: Pins1,2 and 3 shorted together and pin4 and pin6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{AC}	—	—	240	Vac
Forward current	I_F	15	20	25	mA
Peak on-state current	I_{TP}	—	—	1	A
Operating temperature	T_{opr}	-25	—	85	°C

Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

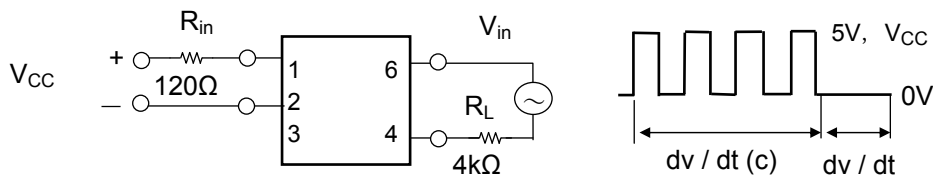
Electrical Characteristics (Ta = 25°C)

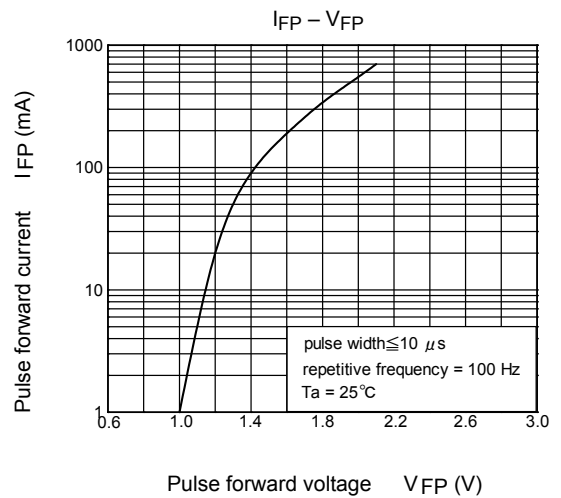
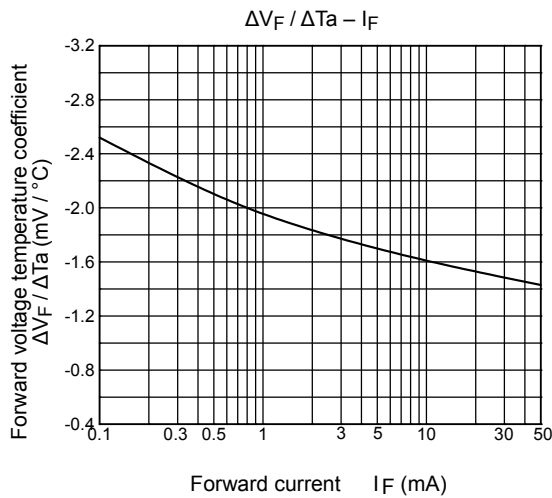
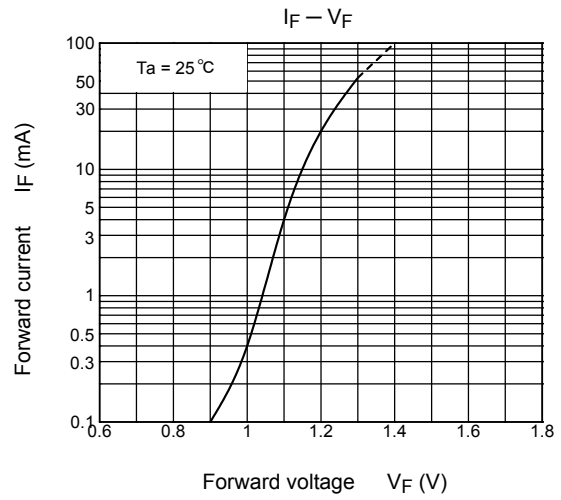
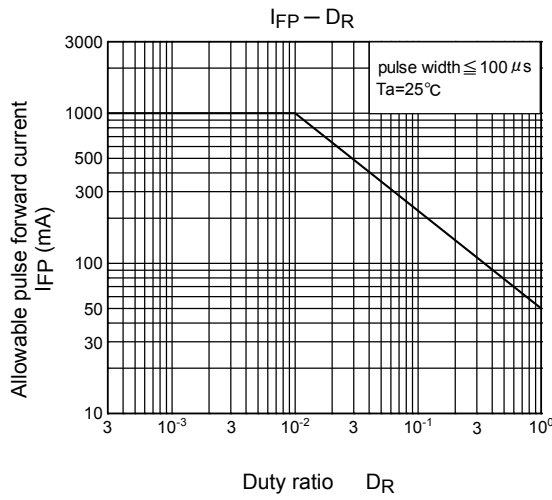
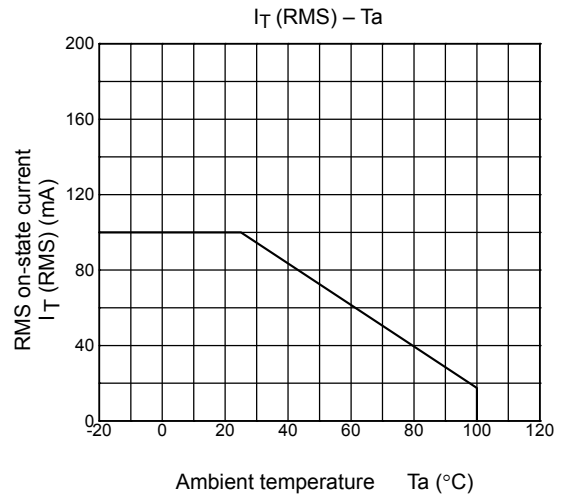
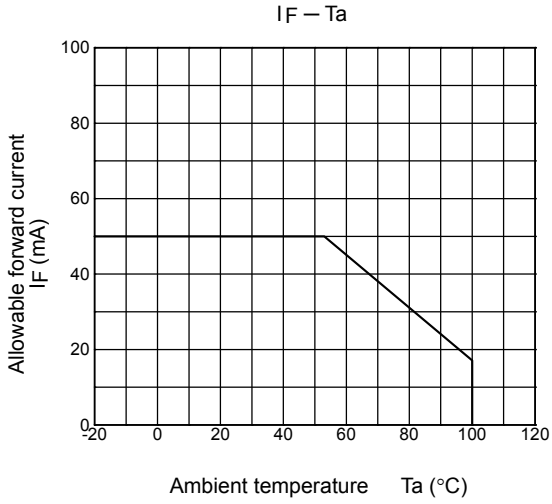
Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1\text{MHz}$	—	30	—	pF
Detector	Peak off-state current	I_{DRM}	$V_{DRM} = 800\text{V}$	—	10	1000	nA
	Peak on-state voltage	V_{TM}	$I_{TM} = 100\text{mA}$	—	1.7	3.0	V
	Holding current	I_H	—	—	0.6	—	mA
	Critical rate of rise of off-state voltage	dv/dt	$V_{in} = 240 \text{ Vrms}, T_a = 85^\circ\text{C}$ (Note 2)	200	500	—	$\text{V}/\mu\text{s}$
	Critical rate of rise of commutating voltage	$dv/dt(c)$	$V_{in} = 60 \text{ Vrms}, I_T = 15 \text{ mA}$ (Note 2)	—	0.2	—	$\text{V}/\mu\text{s}$

Coupled Electrical Characteristics (Ta = 25°C)

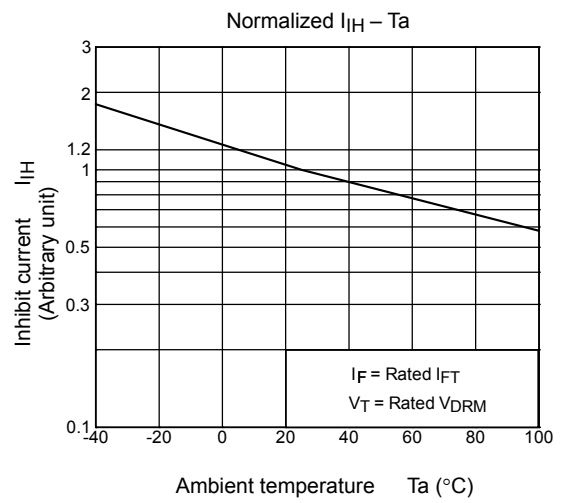
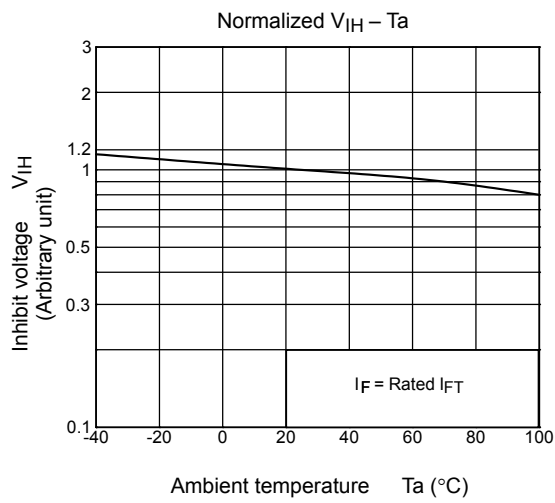
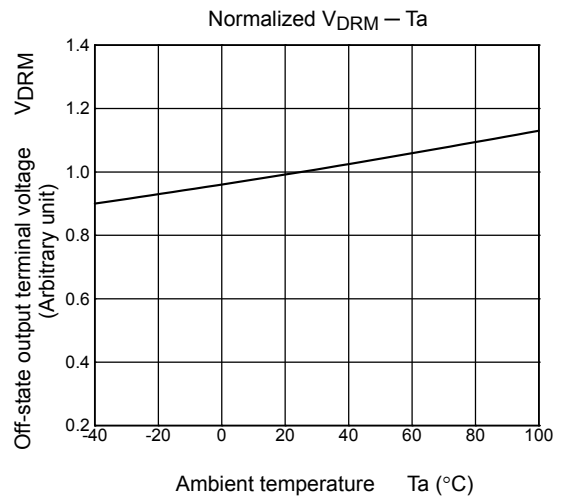
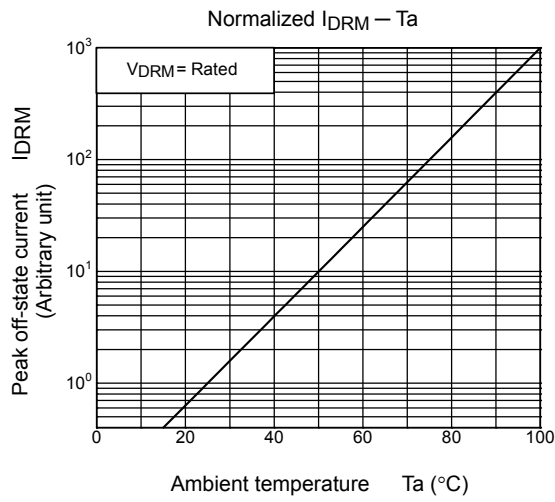
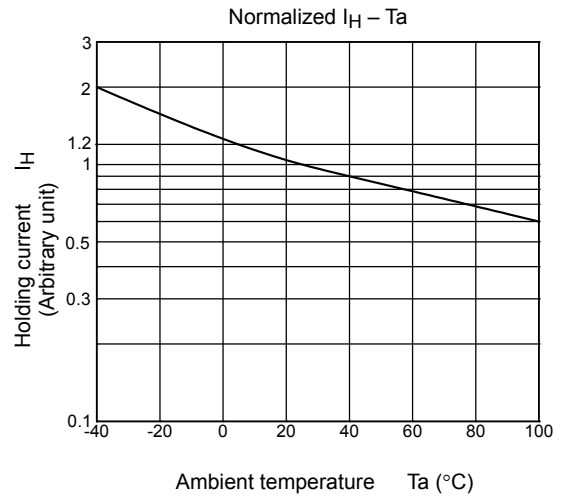
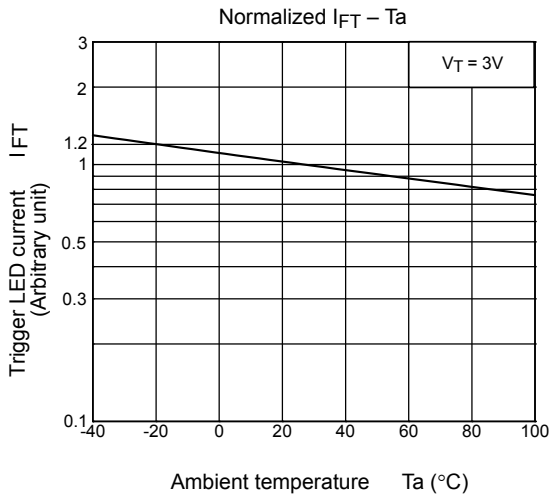
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Trigger LED current	I_{FT}	$V_T = 3\text{V}$	—	5	10	mA
Inhibit voltage	V_{IH}	$I_F = \text{Rated } I_{FT}$	—	—	50	V
Leakage in inhibited state	I_{IH}	$I_F = \text{Rated } I_{FT}, V_T = \text{Rated } V_{DRM}$	—	200	600	μA
Capacitance (input to output)	C_S	$V_S = 0, f = 1\text{MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	1×10^{12}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1minute	5000	—	—	Vrms
		AC, 1second,in oil	—	10000	—	
		DC, 1minute,in oil	—	10000	—	Vdc

(Note 2) dv/dt test circuit





* The above graphs show typical characteristics.



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